

QS30EXQPMA Photoelectric Sensor – Opposed Mode Sensor (Emitter)



Technical data

Туре	QS30EXQPMA
ID no.	3072062
Optical data	
Function	Opposed mode sensor
Operating mode	Emitter
Light type	IR
Wavelength	875 nm
Range	0213000 mm
Operating voltage	1030 VDC
No-load current	≤ 70 mA
Readiness delay	≤ 100 ms
Response time typical	< 30 ms
Mechanical data	
Design	Rectangular with thread, QS30
Dimensions	Ø 30 x 35 x 22 x 49 mm
Housing material	Plastic, Thermoplastic material, Yellow
Lens	plastic, Zeonex
Electrical connection	Cable with connector, M12 × 1, 0.15 m, PUR
Number of cores	5
Ambient temperature	-20+60 °C
Protection class	IP67
Power-on indication	LED, Green
Excess gain indication	LED
Tests/approvals	
MTTF	402 years acc. to SN 29500 (Ed. 99) 40 °C
Approvals	CE



Features

- Cable with male end M12 × 1, 5-pin, PUR, 150 mm
- Protection class IP67
- LED all-round visible
- Selectable operating frequency, protection against crosstalk
- Emitter LED, switchable

Wiring diagram



Functional principle

Opposed mode sensors consist of an emitter and receiver. They are installed opposite to each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Large distance operation is possible due to an excellent light/dark contrast and an extremely high excess gain.

Excess gain curve Excess gain in relation to the distance





Accessories

